

## **100907C** RD183-82.5-10W- 183 MHz Dispersive Delay Line 82.5 MHz Bandwidth

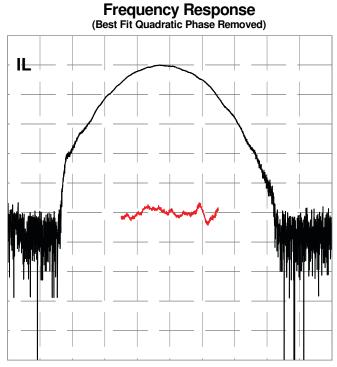
## **Specifications**

Parameter	Symbol	Min	Typical	Max	Unit
Center Frequency	F <sub>0</sub>		183		MHz
Bandwidth	В		82.5		MHz
Dispersion	Т		10		µsec
Delay	To	7.52	7.547	7.56	µsec
Insertion Loss	IL		42.6	45	dB
Slope	S <sub>0</sub>	-0.122	-0.121	-0.12	µs/MHz
Pulse Width at -3 dB			0.0166	0.0169	µsec
Sidelobes for $ t - T_0  < T$			-34.5	-28	dB
Time Spurious for $ t - T_0  > T$			-69	-65	dB
Substrate Material	128YX-LN				

#### Notes

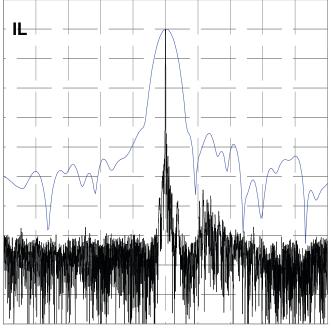
- 1. Center Frequency (F<sub>0</sub>) and Bandwidth (B) are defined, not measured. Dispersion (T) is defined as  $|B^*S_0|$ .
- 2. Insertion Loss is the minimum loss for  $|f F_0| < .5B$
- 3. Delay and Slope determined by best fit quadratic pulse in  $|f F_0| < .5B$ .
- 4. Specifications are at 22 °C only. Unit will operate undamaged from -54 °C to 125 °C with shifts dF<sub>0</sub> = -x \* F<sub>0</sub>, dT<sub>0</sub> = x \* (T<sub>0</sub> + S<sub>0</sub> \* F<sub>0</sub>), dS<sub>0</sub> = x \* 2 \* S<sub>0</sub>, where x = 75E-6 \* (temperature – 22 °C)

## **Typical Performance**



10 dB/div, 10 deg/div, 15.000 MHz/div

### Compressed Pulse Response FFT(Frequency Response\*Cos(0.5\*PI\*MIN(1,MAX(0,|f-F0|\*2.4/82.5-1.2)))^2)



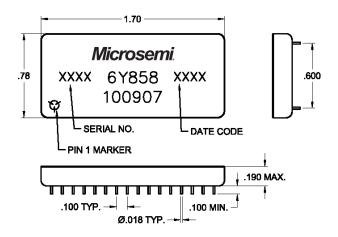
10 dB/div, 2.133 us/div, 0.040 us/div



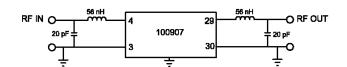
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### **Package Outline**



## Matching





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